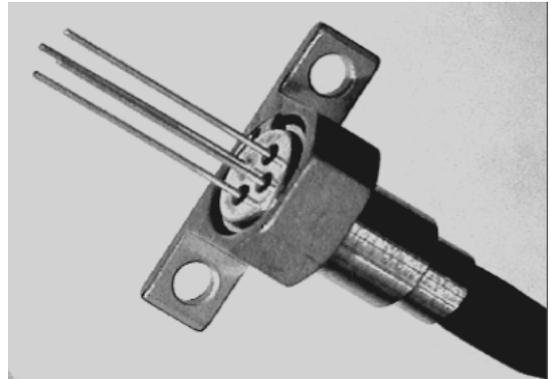


## Target Specification 1550nm DFB Laser in Coaxial Package with SM-Pigtail, High Power

- Designed for application in high-speed and long-haul fiber-optic networks
- Laser Diode with Multi-Quantum-Well and gain coupled structure
- Suitable for bit rates up to 622 Mbit/s (STM-4) without thermoelectric cooler and optical isolator
- Ternary photodiode at rear mirror for monitoring and control of radiant power
- Hermetically sealed subcomponent, similar to TO 18
- SM Pigtail with optional flange



### Maximum Ratings

Output power ratings refer to the SM fiber output. The operating temperature of the submount is identical to the case temperature.

These are absolute stress ratings only. Values above maximum ratings can cause permanent damage to the device.

Module	Symbol	Values		Unit
		Min.	Max.	
Operating Temperature range at case	$T_C$	0	70	°C
Storage Temperature range	$T_{std}$	-40	85	°C
Soldering Temperature $t_{max} = 10$ s, 2 mm distance from bottom edge of case	$T_S$		260	°C

Laserdiode	Symbol	Values		Unit
		Min.	Max.	
Direct forward current	$I_{F_{max}}$		120	mA
Radiant power CW	$\Phi_{av}$		4	mW
Reverse Voltage	$V_{R_{max}}$		2	V

Monitor Diode	Symbol	Values		Unit
		Min.	Max.	
Reverse Voltage	$V_{R_{max}}$		10	V

## Characteristics

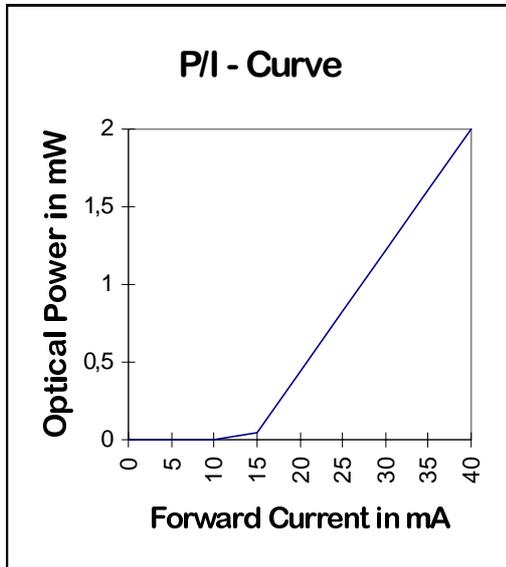
All optical data refer to a coupled 10/125 $\mu$ m SM fiber, Tc =25°C.

Laser Diode	Symbol	Values		Unit
		Min.	Max.	
Optical Peak Output Power	$\Phi_{pk}$	2,4		mW
Optical Average Output Power	$\Phi_{av}$	1,0		mW
Emission wavelength center of range $\Phi_{av} = 1 \text{ mW}^1$	$\lambda$	1530	1570	nm
Spectral bandwidth $\Phi_{av} = 1 \text{ mW}$ (RMS)	$\Delta\lambda$		0,1	nm
Side mode suppression ratio	SSR	30		dB
Threshold current (0...+70°C)	$I_{th}$		55	mA
Forward voltage $\Phi_{av} = 1 \text{ mW}$	$V_F$		1,5	V
Radiant power at threshold	$\Phi_{eth}$		80	$\mu$ W
Slope Efficiency (0...+70°C)	$\eta$	30	150	mW/A
Differential series resistance	$r_S$		8	$\Omega$
Rise Time/Fall Time	$t_R, t_F$		0,5	ns
Temperature Coefficient of the emission wavelength center	$TC\lambda$		0,15	nm/K

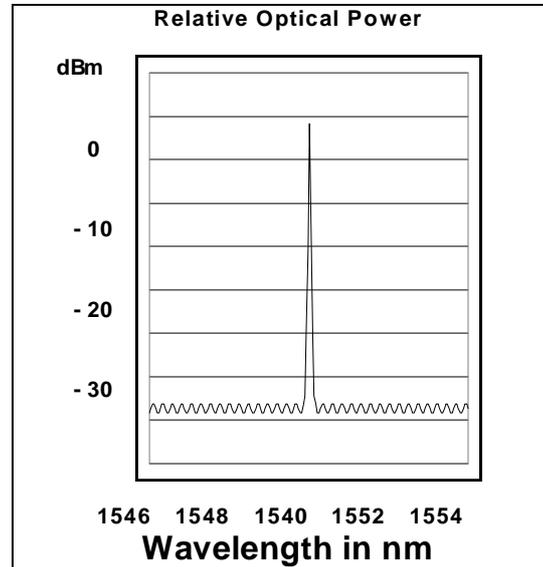
Monitor Diode	Symbol	Values		Unit
		Min.	Max.	
Dark Current, $V_R = 5 \text{ V}, \Phi_{av} = 0$			10	nA
Photocurrent, $\Phi_{av} = 1 \text{ mW}$	$I_P$	100	1700	$\mu$ A

1) Wavelength selection according ITU-Standard available on demand.

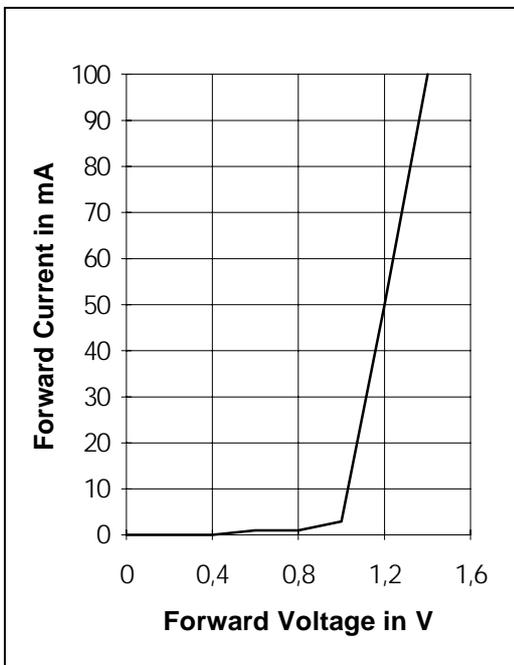
**Laser Diode**  
Radiant Power in Singlemode Fibre



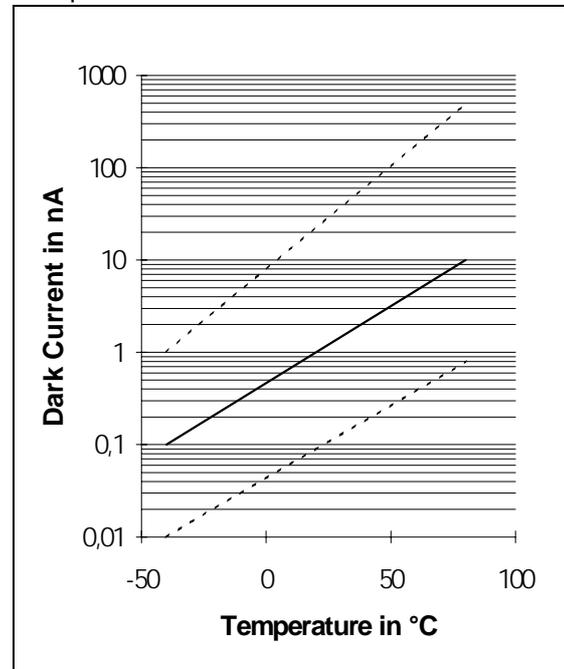
**Relative Radiant Power**  
 $\Phi_{av} = f(\lambda)$



**Laser Forward Current**  
 $I_F = f(V_F)$



**Monitor Diode Dark Current  $I_R = f(T_A)$**   
 $\Phi_{port} = 0, V_R = 5V$



**Ordering Information:**

<b>Type</b>	<b>Ordering Code</b>	<b>Connector/Flange</b>
STH91004G	Q62702-Pxxxx	FC / without flange
STH91004A	Q62702-Pxxxx	DIN / without flange
STH91005G	Q62702-Pxxxx	FC / with flange
STH91005A	Q62702-Pxxxx	DIN / with flange

**Component with other connector types on request**

**Package Dimension:**

STH91004x

STH91005x (with flange)

